

NCE P-Channel Super Trench Power MOSFET

Description

The NCEP40PT15D uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

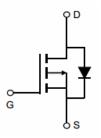
General Features

- V_{DS} =-40V, I_{D} =-150A $R_{DS(ON)}$ =2.8mΩ (typical) @ V_{GS} =-10V $R_{DS(ON)}$ =3.8mΩ (typical) @ V_{GS} =-4.5V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED! 100% ΔVds TESTED!



Schematic Diagram



Marking and pin assignment



TO-263-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP40PT150D	NCEP40PT15D	TO-263-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-40	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	-150	Α
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	-120	Α
Pulsed Drain Current	I _{DM}	-600	Α
Maximum Power Dissipation	P _D	250	W
Derating factor		1.67	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	1345	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$



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NCEP40PT15D

Thermal Characteristic

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-40		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-40V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20 V , V_{DS} =0 V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =-250μA	-0.8	-1.2	-1.8	V
Drain Course On State Desistance	Б	V _{GS} =-10V, I _D =-75A	-	2.8	3.4	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-75A	-	3.8	4.6	mΩ
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-75A	-	30	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	V _{DS} =-20V,V _{GS} =0V,	-	8940	-	PF
Output Capacitance	Coss		-	1900	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	45	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	18	-	nS
Turn-on Rise Time	t _r	V_{DD} =-20V, I_D =-75A	-	13	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10 V , R_{G} =1.6 Ω	-	90	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg	\/ - 20\/ L - 75A	-	104.4	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-20V, I_{D} =-75A, V_{GS} =-10V	-	20.8		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =-10V	-	13.5		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =-75A	-		-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-150	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =-75A	-		35	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-		85	nC

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\!\!\mathrm{C}$,V_DD=-20V,V_G=-10V,L=0.5mH,Rg=25 $\!\Omega$



Typical Electrical and Thermal Characteristics

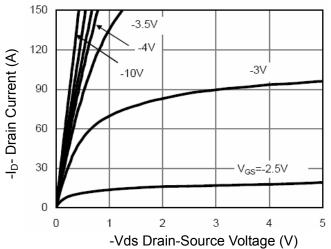


Figure 1 Output Characteristics

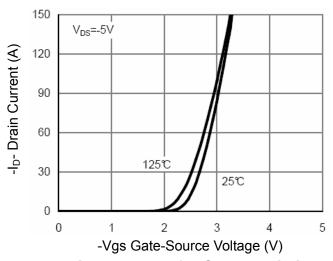


Figure 2 Transfer Characteristics

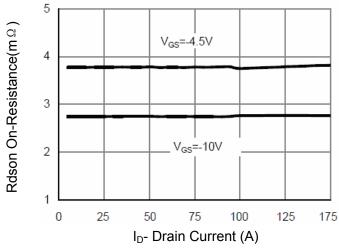


Figure 3 Rdson- Drain Current

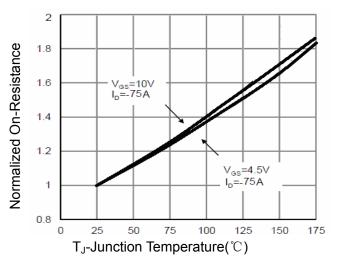


Figure 4 Rdson-JunctionTemperature

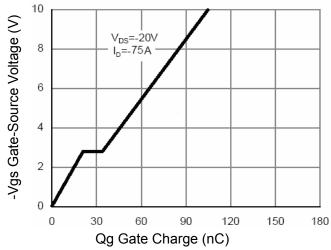


Figure 5 Gate Charge

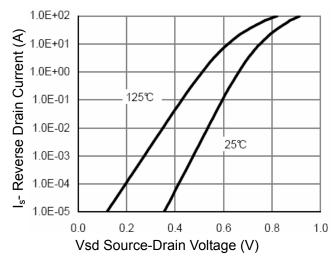


Figure 6 Source- Drain Diode Forward



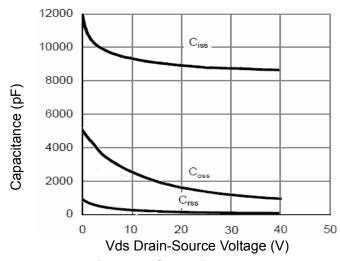


Figure 7 Capacitance vs Vds

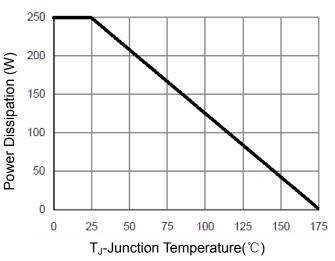


Figure 9 Power De-rating

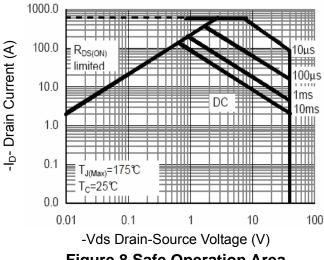


Figure 8 Safe Operation Area

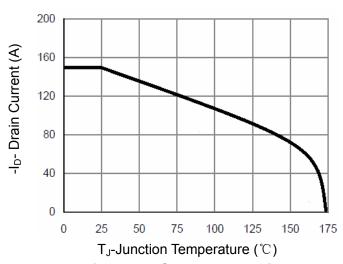


Figure 10 Current De-rating

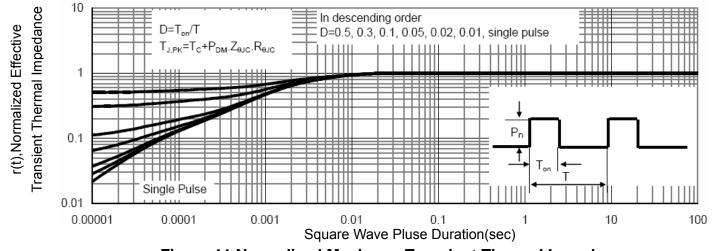
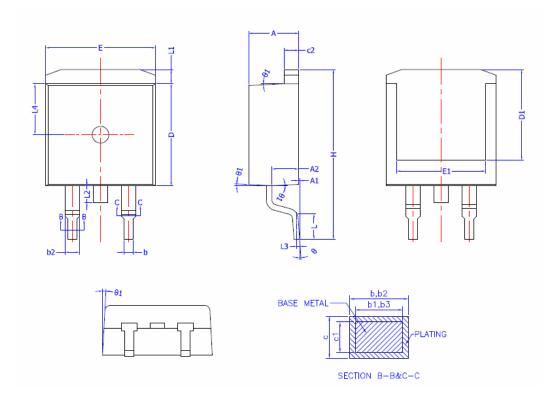


Figure 11 Normalized Maximum Transient Thermal Impedance



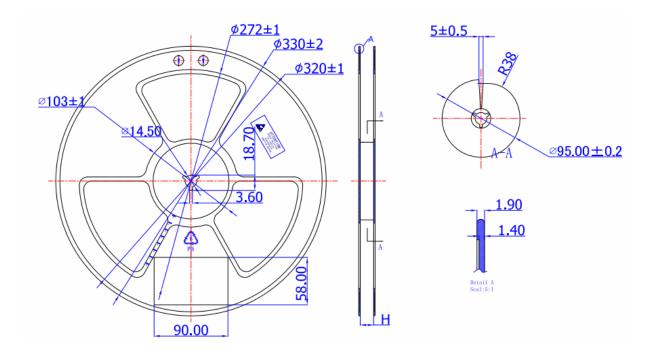
TO-263-2L Package Information

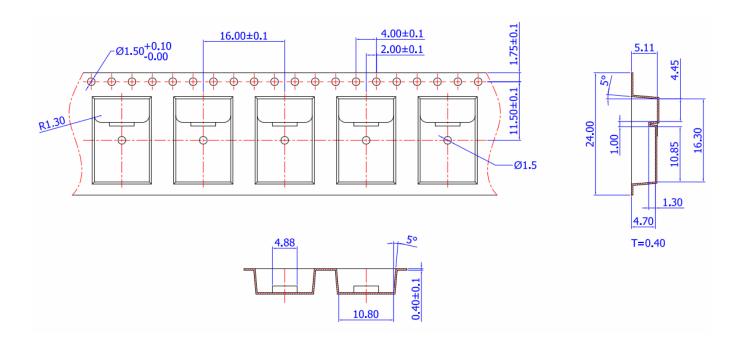


COMMON DIMENSIONS (UNITS OF MEASURE =MILLIMETER)

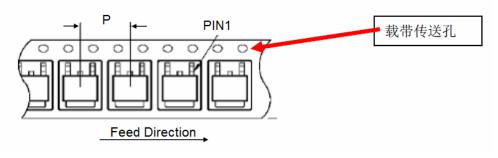
SYMBOL	MIN	NOM	MAX	
Α	4.40	4.50	4.60	
A1	0	0.10	0.25	
A2	2,20	2,40	2,60	
b	0,76	_	0,89	
b1	0,75	0,80	0,85	
b2	1,23		1,37	
b3	1,22	1,27	1,32	
С	0,47	_	0,60	
c1	0.46	0,51	0.56	
c2	1,25	1,30	1,35	
D	9.10	9,20	9.30	
D1	8,00	—	—	
E	9.80	9.90	10.00	
E1	7.80	_	_	
е	2.54 BSC			
Н	14.90	15.30	15.70	
L	2.00	2,30	2.60	
L1	1.17	1.27	1.40	
L2	_	_	1,75	
L3	0.25BSC			
L4	4.60 REF			
θ	0°	_	8°	
θ1	1°	3°	5°	





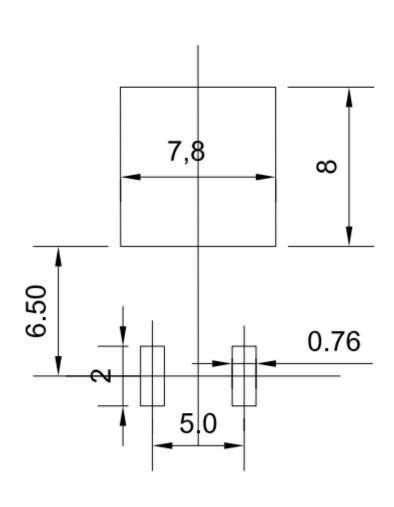


注:产品编入卷盘中时,产品第一支脚(PIN 1)方向朝向载带传送孔。如下图所示。





焊盘



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